

Substitute for form 1449A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

Sheet 1 of 1

Complete if Known

Application Number	09/883795
Filing Date	June 18, 2001
First Named Inventor	Forbes, Leonard
Group Art Unit	2814
Examiner Name	Doan, Theresa
Attorney Docket No:	303.355US4

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OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS

Examiner Initials *	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ¹
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EXAMINER

Doan

DATE CONSIDERED

10/15/03

Substitute Disclosure Statement form (PTO) 1449A
EXAMINER: Initial if reference is considered; whether or not citation is in conformity with MPEP 609. Draw line through citation if not in conformity and not considered. Include copy of this form with next communication to applicant. Applicant's unique citation designation number (optional). Applicant is to place a check mark here if English language Translation is attached.